



Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



## SILICON PLANAR EPITAXIAL TRANSISTORS

**BC327/A BC328 PNP  
BC337/A BC338 NPN**



TO-92

**TO-92  
Plastic Package  
RoHS compliant**

### FEATURE:

1. This product is available in AEC-Q101 Compliant and PPAP Capable also.

**Note:** For AEC-Q101 compliant products, please use suffix -AQ in the part number while ordering.

### APPLICATIONS:

General Purpose Transistors Best Suited for use in Driver and Output Stages of Audio Amplifier

### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	BC327/337	BC327A/337A	BC328/338	UNIT
Collector Emitter Voltage	$V_{CEO}$	45	60	25	V
Collector Emitter Voltage	$V_{CES}$	50	60	30	V
Emitter Base Voltage	$V_{EBO}$	5			V
Collector Current Continuous	$I_C$	800			mA
Collector Current Peak	$I_{CM}$	1000			mA
Emitter Current Peak	$I_{EM}$	1000			mA
Base Current Continuous	$I_B$	100			mA
Base Current Peak	$I_{BM}$	200			mA
Power Dissipation at Ta=25°C	$P_D$	625			mW
Derate Above 25°C		5			mW/°C
Operating And Storage Junction Temperature Range	$T_j, T_{stg}$	-65 to +150			°C

### THERMAL RESISTANCE

Junction to Ambient in free air	$R_{th(j-a)}$	200	°C/W
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BC327\_338

Rev04 12072022EM

**ELECTRICAL CHARACTERISTICS at** (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector Emitter Voltage	$V_{CEO}$	$I_C=1mA, I_B=0$	BC327/337	45	--	--	V
			BC327A/337A	60	--	--	V
			BC328/338	25	--	--	V
Collector Emitter Voltage	$V_{CES}$	$I_C=100mA, I_E=0$	BC327/337	50	--	--	V
			BC327A/337A	60	--	--	V
			BC328/338	30	--	--	V
Emitter Base Voltage	$V_{EBO}$	$I_E=10mA, I_C=0$	5.0	--	--	V	
Collector Cut Off Current	$I_{CBO}$	$V_{CB}=20V, I_E=0,$	--	--	100	nA	
		$V_{CB}=20V, I_E=0, T_J=150\text{ }^\circ\text{C}$	--	--	5	$\mu\text{A}$	
Emitter Cut Off Current	$I_{EBO}$	$V_{EB}=5V, I_C=0$	--	--	10	$\mu\text{A}$	
Collector Emitter Saturation Voltage	$V_{CE(sat)}^1$	$I_C=500mA, I_B=50mA$	--	--	0.7	V	
Base Emitter On Voltage	$V_{BE(on)}^1$	$I_C=500mA, V_{CE}=1V$	--	--	1.2	V	
DC Current Gain	$h_{FE}$	$I_C=100mA, V_{CE}=1V$	BC327A/337A	100	--	400	
			BC327/328, BC337/338	100	--	600	
		BC327/328, BC337/338	Group-10	63	--	160	
			Group-16	100	--	250	
			Group-25	160	--	400	
			Group-40	250	--	600	
	$I_C=500mA, V_{CE}=1V$	40	--	--			

**SMALL SIGNAL CHARACTERISTICS**

Transistors Frequency	$f_T$	$I_C=10mA, V_{CE}=5V, f=35MHz$	NPN	--	200	--	MHz
			PNP	--	100	--	MHz
Output Capacitance	$C_{ob}$	$V_{CB}=10V, I_E=0, f=1MHz$	NPN	--	5	--	pF
			PNP	--	8	--	pF

**Note:**

1. Pulse Condition: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
2. For PNP device voltage and current values will be negative (-).

### Recommended Reflow Solder Profiles

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

Figure 1 shows the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.

Figure 1

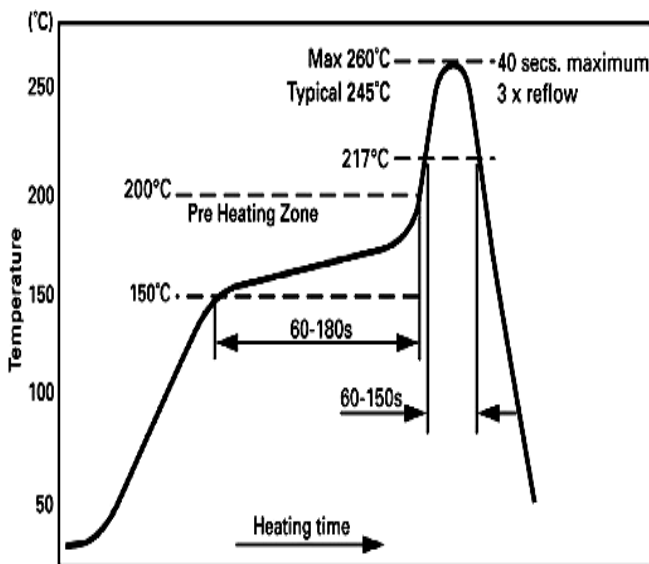
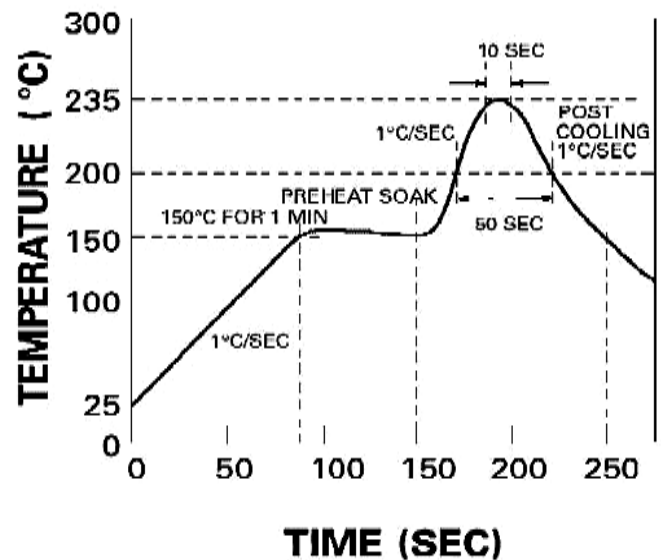


Figure 2

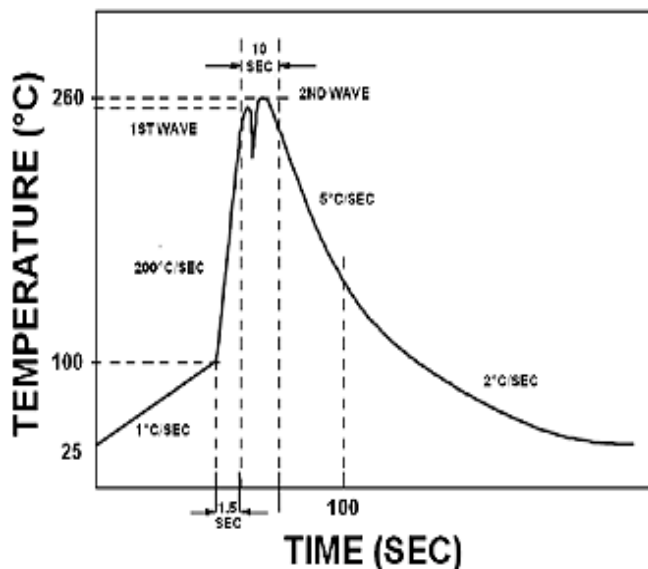


#### Reflow profiles in tabular form

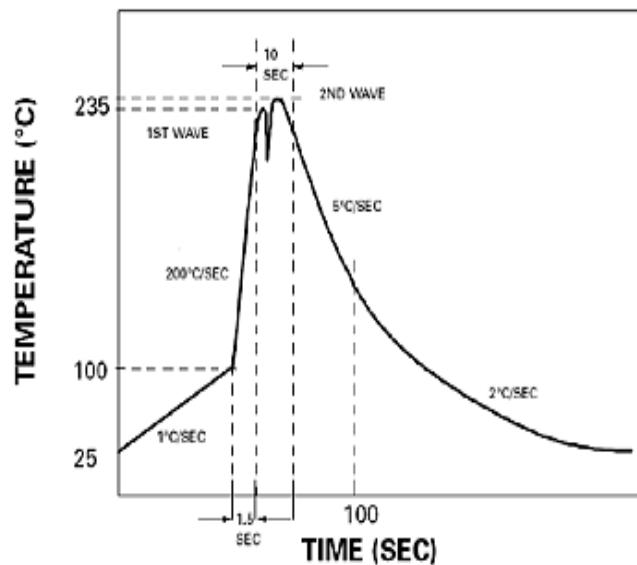
Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~3°C/second	~3°C/second
<b>Preheat</b>		
– Temperature Range	150-170°C	150-200°C
– Time	60-180 seconds	60-180 seconds
Time maintained above:		
– Temperature	200°C	217°C
– Time	30-50 seconds	60-150 seconds
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	40 seconds
Ramp-Down Rate	3°C/second max.	6°C/second max.

### Recommended Wave Solder Profiles

The Recommended solder Profile For Devices with Pb-free terminal plating where a Pb-free solder is used



The Recommended solder Profile For Devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with leaded solder



### Wave Profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~200°C/second	~200°C/second
Heating rate during preheat	Typical 1-2, Max 4°C/sec	Typical 1-2, Max 4°C/Sec
Final preheat Temperature	Within 125°C of Solder Temp	Within 125°C of Solder Temp
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	10 seconds
Ramp-Down Rate	5°C/second max.	5°C/second max

## TYPICAL CHARACTERISTICS CURVES

Fig 1: Static Characteristic

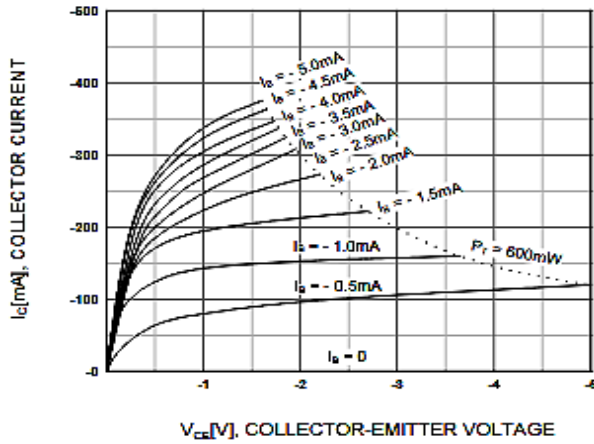


Fig 2: DC current Gain

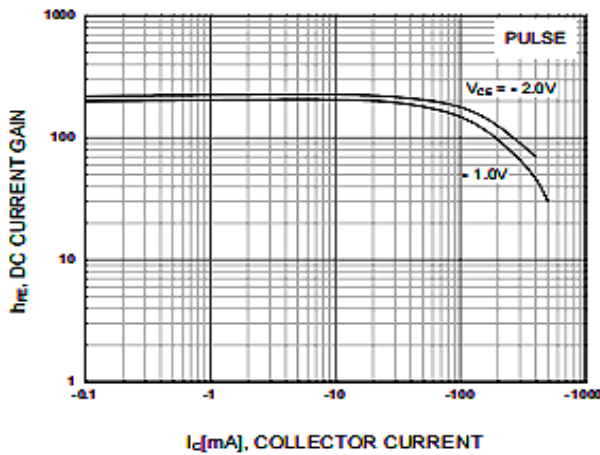


Fig 3: Base-Emitter On Voltage

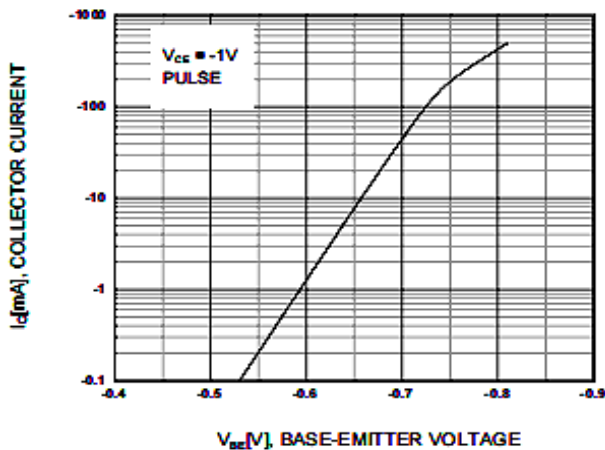


Fig 4: Static Characteristic

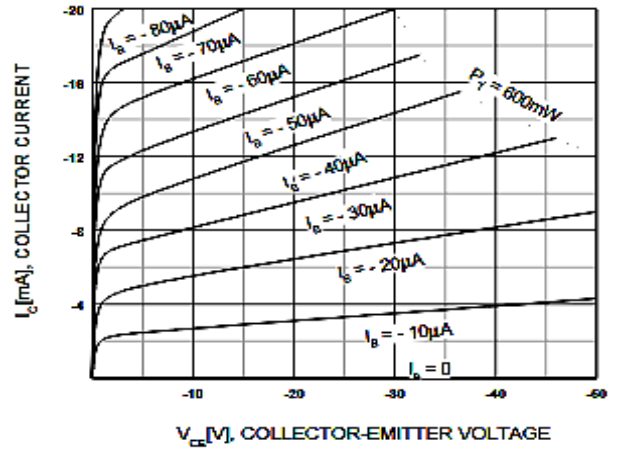


Fig 5: Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

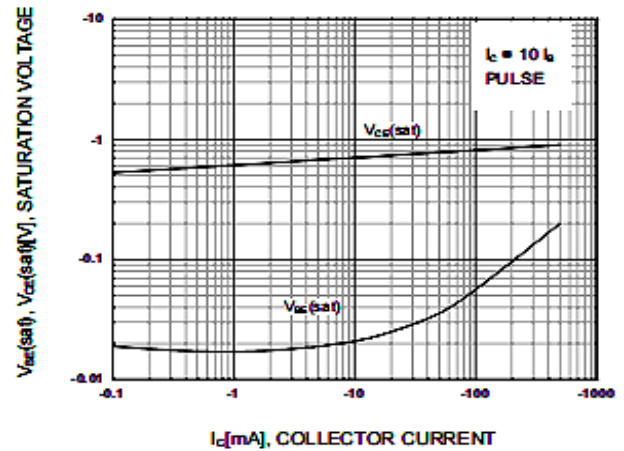
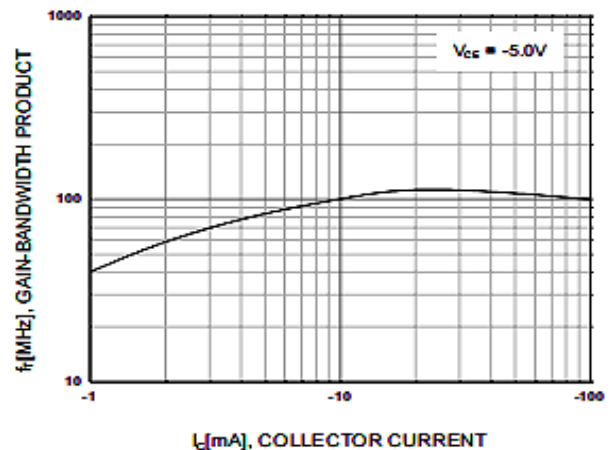
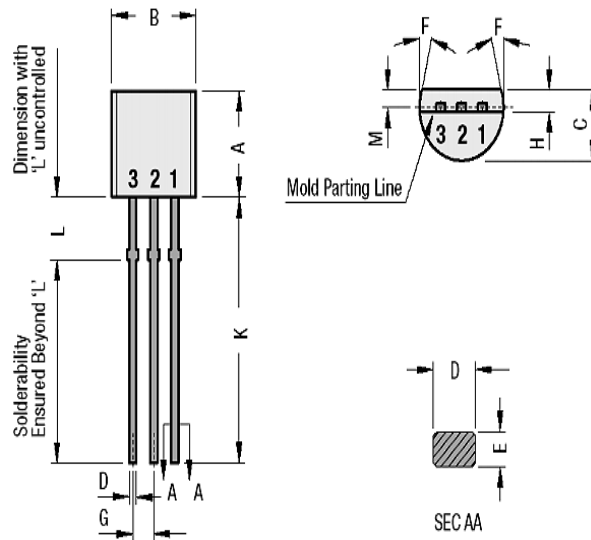


Fig 6: Gain Bandwidth Product



## PACKAGE DETAILS

### TO-92 Leaded Plastic Package

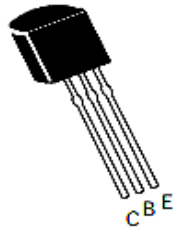


DIM	MIN	MAX
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.40	0.55
E	0.30	0.55
F	5°	
G	1.14	1.40
H	1.20	1.40
K	12.7	
L	1.982	2.082
M	1.03	1.20

All dimensions are in mm

### PIN CONFIGURATION

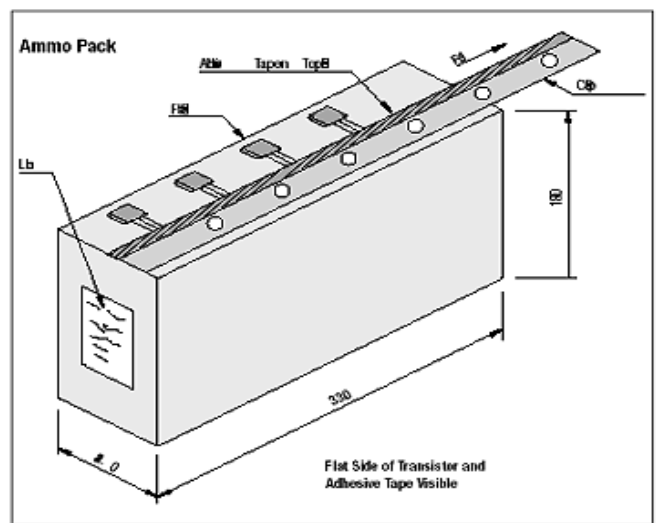
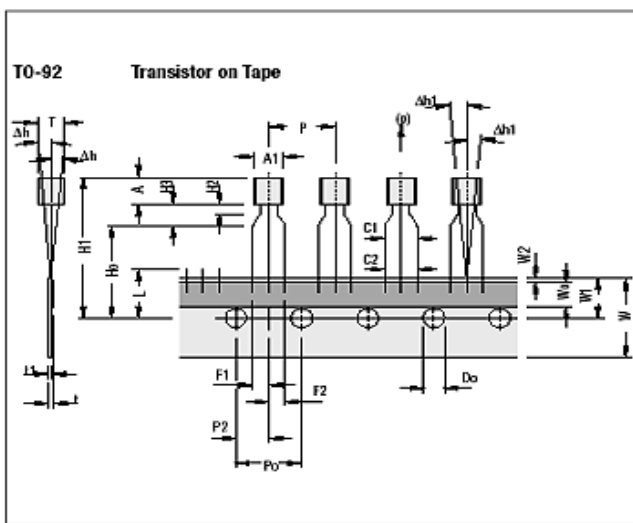
1. Emitter
2. Base
3. Collector



## Packaging Information

Package/Case Type	Packaging Type	Std. Packing		Inner Carton		Outer Carton		
		Qty	Qty	Size L x W x H (cm)	Gross Weight (Kg)	Qty	Size L x W x H (cm)	Gross Weight (Kg)
TO-92	Bulk	1,000	5K	19x19x8	1.10	80K	43x40x35	20.0
	T&A	2,000	2K	32x4.5x20	0.70	40K	43x40x35	15.20

### TO-92 Tape and Ammo Packaging



All Dimensions are in mm

## Tape Specifications

Item description	Symbol	TO-92			
		Min	Nom	Max	Tol
Body width	A1	4.45		5.20	
Body height	A	4.32		5.33	
Body thickness	T	3.18		4.19	
Pitch of component <sup>Cr</sup>	P		12.7		±1.0
Feed hole pitch <sup>S1</sup>	Po		12.7		±0.3
Feed hole center to component centre <sup>S2</sup>	P2		6.35		±0.4
Comp. alignment, Side view <sup>S3</sup>	Dh		0	1.0	
Comp. alignment, Front view <sup>S3</sup>	Dh1		0	1.3	
Tape width <sup>Cr</sup>	W		18		±0.5
Hold down tape width <sup>Cr</sup>	Wo		6		±0.2
Hole position	W1		9		+0.7 -0.5
Hold-down tape position	W2	0.0		0.7	
Lead wire clinch height	Ho		16		±0.5
Component height	H1			24.0	
Length of snipped leads	L			11.0	
Feed hole diameter <sup>Cr</sup>	Do		4		±0.2
Total tape thickness <sup>S4</sup>	t			1.2	
Lead-to-lead distance <sup>Cr</sup>	F1, F2	2.4		2.7	
Stand off	H2	0.45		1.45	
Clinch height	H3			3.0	

### Taping Specification

- Maximum alignment deviation between leads not to be greater than 0.20 mm.
- Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
- Hold down tape not to exceed beyond the edge(s) carrier tape and there shall be no exposure of adhesive.
- No more than 3 consecutive missing components is permitted.
- A tape trailer, having at least three feed holes is required after the last component.
- Splices shall not interfere with the sprocket feed holes.

<sup>S1</sup> Cumulative pitch error 1.0 mm/20 pitch.

<sup>S2</sup> To be measured at bottom of clinch.

<sup>S3</sup> At top of body.





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Lead parallelismCr	C1-C2			0.22	
Pull-out force	(p)	6N			

§4 t1 = 0.3 – 0.6 mm  
 Cr Critical Dimension.

All Dimensions are in mm





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## Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

### Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

### Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level		
Level	Time	Condition
1	Unlimited	≤30 °C / 85% RH
2	1 Year	≤30 °C / 60% RH
2a	4 Weeks	≤30 °C / 60% RH
3	168 Hours	≤30 °C / 60% RH
4	72 Hours	≤30 °C / 60% RH
5	48 Hours	≤30 °C / 60% RH
5a	24 Hours	≤30 °C / 60% RH
6	Time on Label(TOL)	≤30 °C / 60% RH



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## Customer Notes

### Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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